

## Switching Performance of mm-Wave PIN Diodes for Ultra High Data Rates

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*F. Bosch and O.G. Petersen. "Switching Performance of mm-Wave PIN Diodes for Ultra High Data Rates." 1977 MTT-S International Microwave Symposium Digest 77.1 (1977 [MWSYM]): 212-215a.*

The 300 Mb/s switching performance of 40 to 110 GHz PIN diodes is presented as a function of their storage and fall time, which varied from 2 to 18 and 0.2 to 1.2 ns, respectively.

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